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ON Semiconductor® FDMS86580-F085

N-Channel PowerTrench[®] MOSFET

60 V, 50 A, 9.6 mΩ

Features

- Typical $R_{DS(on)}$ = 7.9 m Ω at V_{GS} = 10V, I_D = 50 A
- Typical Q_{g(tot)} = 20 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter	Ratings	Units		
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	Α	
	Pulsed Drain Current	T _C = 25°C	See Figure 4		
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	19	mJ	
P _D	Power Dissipation		75	W	
	Derate Above 25°C		0.5	W/ ^o C	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		2.0	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W	

Notes:

- 1: Current is limited by bondwire configuration.

ROHS

2: Starting T_J = 25°C, L = 20µH, I_{AS} = 44A, V_{DD} = 60V during inductor charging and V_{DD} = 0V during time in avalanche. 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity	
FDMS86580	FDMS86580-F085	Power 56	13"	12mm	3000units	

Bottom

D

D

2

S S

S G

Тор

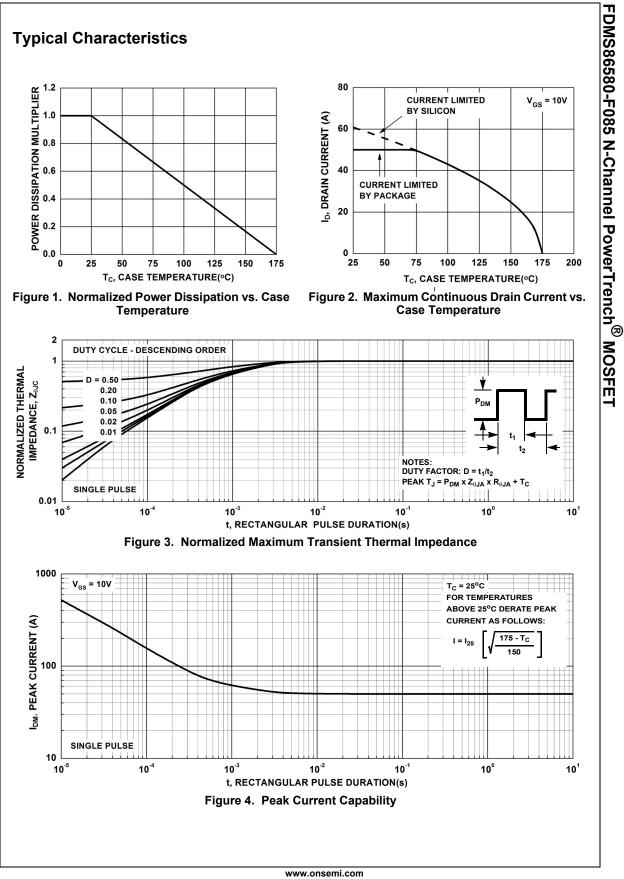
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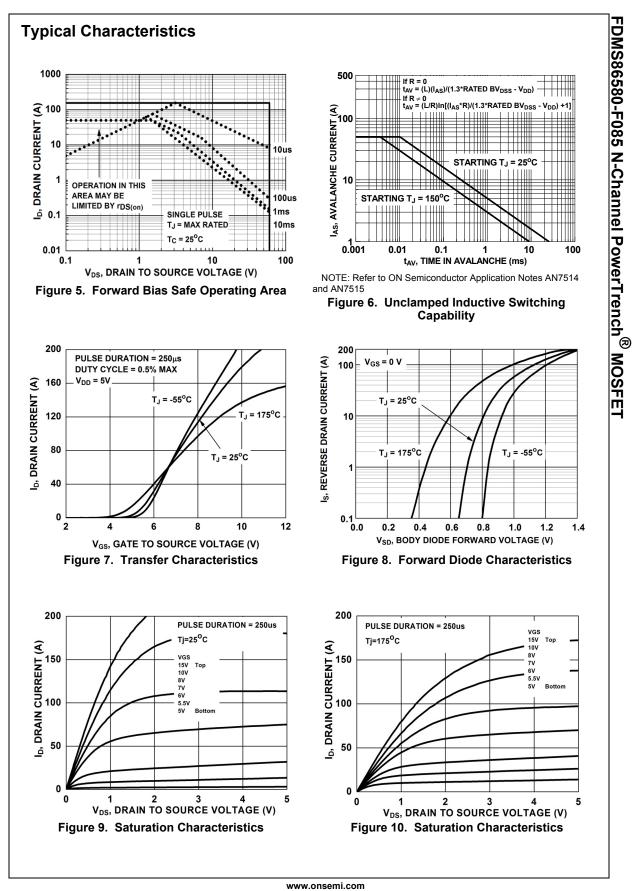
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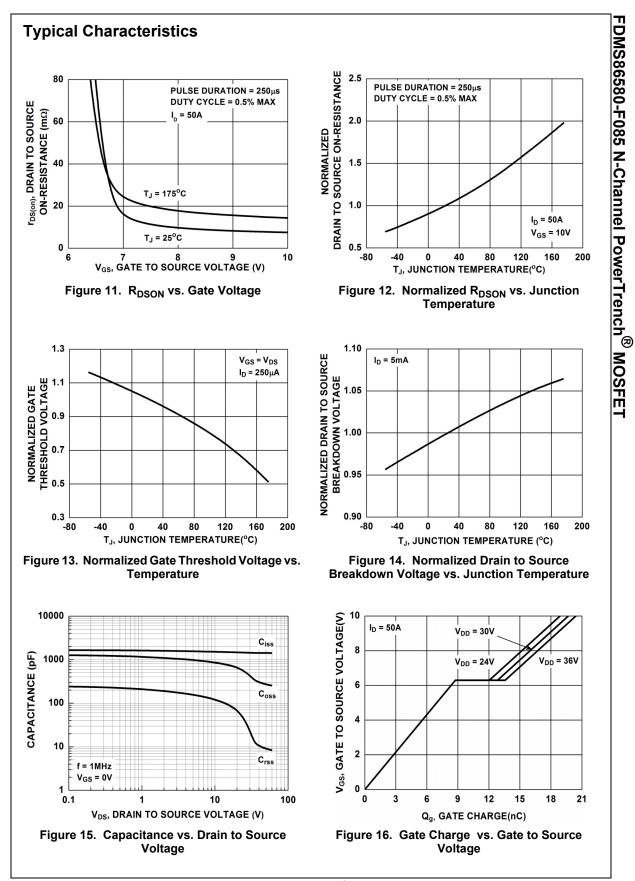
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS}	= 0V	60	-	-	V
		V _{DS} =60V, T _J		-	-	1	μA
I _{DSS}	Drain-to-Source Leakage Current	$V_{GS} = 0V$ T_J	= 175 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.5	4.2	V
	Daria ta Causa On Desistanos	I _D = 50A, T _J	= 25°C	-	7.9	9.6	mΩ
R _{DS(on)}	Drain to Source On Resistance	V_{GS} = 10V T _J	= 175°C (Note 4)	-	15.6	19.5	mΩ
Dynami	c Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	1430	-	pF
C _{oss}	Output Capacitance			-	440	-	pF
C _{rss}	Reverse Transfer Capacitance			-	25	-	pF
R _q	Gate Resistance	V _{GS} = 0.5V, f = 1MHz		-	1.8	-	Ω
Q _{g(ToT)}	Total Gate Charge	$V_{GS} = 0 \text{ to } 10V$ $V_{DD} = 30V$		-	20	30	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 50A$		-	3	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	9	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	4	-	nC
	ng Characteristics					30	20
t _{on}	Turn-On Delay			-	- 13	30	ns ns
t _{d(on)} t _r	Rise Time	$V_{DD} = 30V, I_D = 50A,$ $V_{GS} = 10V, R_{GEN} = 6\Omega$		-	7	-	ns
t _{d(off)}	Turn-Off Delay			-	, 15	-	ns
t _f	Fall Time			-	5	-	ns
t _{off}	Turn-Off Time			-	-	30	ns
	ource Diode Characteristics			<u> </u>	1	I	I
V	Source to Drain Diade Valtage	I _{SD} = 50A, V _{GS} = 0V I _{SD} = 25A, V _{GS} = 0V		-	0.97	1.3	V
	Source-to-Drain Diode Voltage			-	0.88	1.2	V
V _{SD}	Reverse-Recovery Time	V _{DD} = 48V, I _F = 50A,		-	44	66	ns
v _{SD}	Reverse-Recovery Time		dl _{SD} /dt = 100A/μs				



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